BYC8X-600

Hyperfast power diode

19 October 2017 Product data sheet

1. General description

Hyperfast power diode in a SOD113 (2-lead TO-220F) plastic package.

2. Features and benefits

- Isolated plastic package
- Low reverse recovery current
- Low thermal resistance
- Reduces switching losses in associated MOSFET

3. Applications

- Continuous Current Mode (CCM) Power Factor Correction (PFC)
- Half-bridge/full-bridge switched-mode power supplies
- Half-bridge lighting ballasts

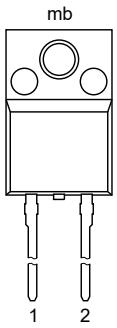
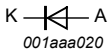
4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions		Min	Typ	Max	Unit
$I_{F(AV)}$	average forward current	$\delta = 0.5$; $T_h \leq 59$ °C; square-wave pulse; Fig. 1; Fig. 2		-	-	8	A
I_{FRM}	repetitive peak forward current	$\delta = 0.5$; $t_p = 25$ µs; $T_h \leq 59$ °C; square-wave pulse		-	-	16	A
I_{FSM}	non-repetitive peak forward current	$t_p = 10$ ms; $T_{j(init)} = 25$ °C; sine-wave pulse		-	-	80	A
		$t_p = 8.3$ ms; $T_{j(init)} = 25$ °C; sine-wave pulse		-	-	88	A
Static characteristics							
V_F	forward voltage	$I_F = 8$ A; $T_j = 150$ °C; Fig. 4		-	1.4	1.85	V
		$I_F = 8$ A; $T_j = 25$ °C		-	2	2.9	V
		$I_F = 16$ A; $T_j = 150$ °C		-	1.7	2.3	V
Dynamic characteristics							
t_{rr}	reverse recovery time	$I_F = 8$ A; $V_R = 400$ V; $dI_F/dt = 500$ A/µs; $T_j = 100$ °C		-	32	40	ns
		$I_F = 1$ A; $V_R = 30$ V; $dI_F/dt = 50$ A/µs; $T_j = 25$ °C		-	30	52	ns
		$I_F = 8$ A; $V_R = 400$ V; $dI_F/dt = 500$ A/µs; $T_j = 25$ °C; Fig. 5		-	19	-	ns

5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	K	cathode	 TO-220F (SOD113)	
2	A	anode		
mb	n.c.	mounting base; isolated		

6. Ordering information

Table 3. Ordering information

Type number	Package		
	Name	Description	Version
BYC8X-600	TO-220F	plastic single-ended package; isolated heatsink mounted; 1 mounting hole; 2-lead TO-220 "full pack"	SOD113

7. Marking

Table 4. Marking codes

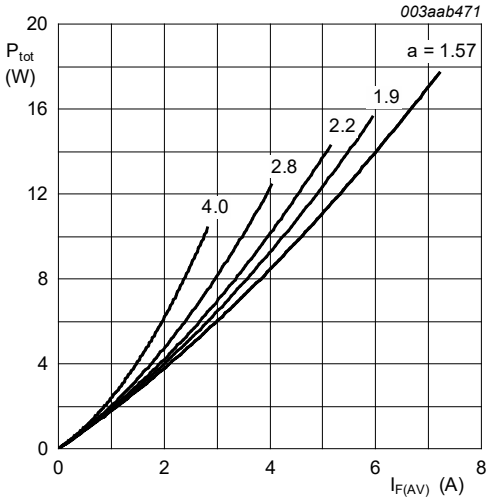
Type number	Marking code
BYT79X-600P	BYT79X-600P

8. Limiting values

Table 5. Limiting values

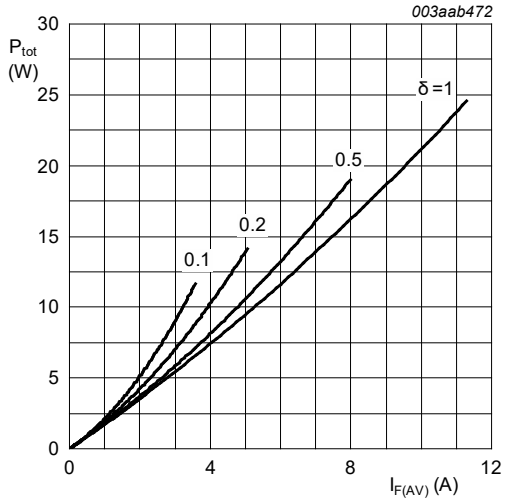
In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
V_{RRM}	repetitive peak reverse voltage			-	600	V
V_{RWM}	crest working reverse voltage			-	600	V
$I_{F(AV)}$	average forward current	δ = 0.5 ; $T_h \leq$ 59 °C; square-wave pulse; Fig. 1; Fig. 2		-	8	A
I_{FRM}	repetitive peak forward current	δ = 0.5 ; t_p = 25 µs; $T_h \leq$ 59 °C; square-wave pulse		-	16	A
I_{FSM}	non-repetitive peak forward current	t_p = 10 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse		-	80	A
		t_p = 8.3 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse		-	88	A
T_{stg}	storage temperature			-40	150	°C
T_j	junction temperature			-	150	°C



$a = \text{form factor} = I_{F(RMS)} / I_{F(AV)}$

Fig. 1. Forward power dissipation as a function of average forward current; sinusoidal waveform; maximum values



$I_{F(AV)} = I_{F(RMS)} \times \sqrt{\delta}$

Fig. 2. Forward power dissipation as a function of average forward current; square waveform; maximum values

9. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions		Min	Typ	Max	Unit
$R_{th(j-h)}$	thermal resistance from junction to heatsink	with heatsink compound; Fig. 3		-	-	4.8	K/W
$R_{th(j-a)}$	thermal resistance from junction to ambient free air			-	55	-	K/W

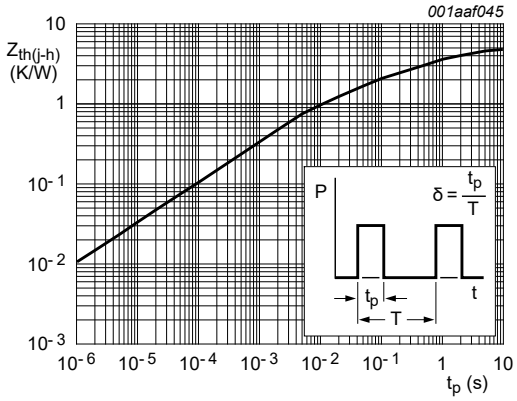


Fig. 3. Transient thermal impedance from junction to heatsink as a function of pulse width

10. Isolation characteristics

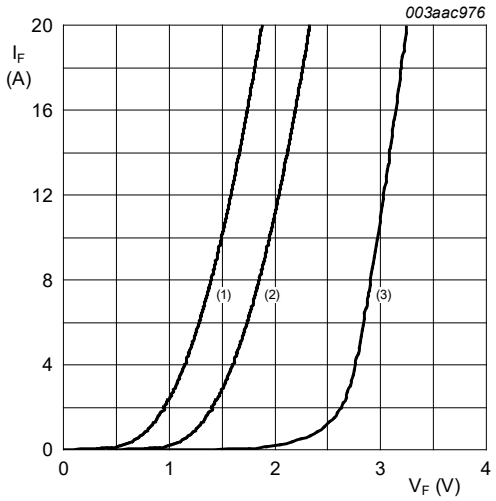
Table 7. Isolation characteristics

Symbol	Parameter	Conditions		Min	Typ	Max	Unit
$V_{isol(RMS)}$	RMS isolation voltage	50 Hz ≤ f ≤ 60 Hz; RH ≤ 65 %; from all pins to external heatsink; sinusoidal waveform; clean and dust free		-	-	2500	V
C_{isol}	isolation capacitance	from cathode to external heatsink		-	10	-	pF

11. Characteristics

Table 8. Characteristics

Symbol	Parameter	Conditions		Min	Typ	Max	Unit
Static characteristics							
V_F	forward voltage	I_F = 8 A; T_j = 150 °C; Fig. 4		-	1.4	1.85	V
		I_F = 8 A; T_j = 25 °C		-	2	2.9	V
		I_F = 16 A; T_j = 150 °C		-	1.7	2.3	V
I_R	reverse current	V_R = 500 V; T_j = 100 °C		-	1.1	3	mA
		V_R = 600 V; T_j = 25 °C		-	9	150	µA
Dynamic characteristics							
t_{rr}	reverse recovery time	I_F = 8 A; V_R = 400 V; dI_F/dt = 500 A/µs; T_j = 100 °C		-	32	40	ns
		I_F = 1 A; V_R = 30 V; dI_F/dt = 50 A/µs; T_j = 25 °C		-	30	52	ns
		I_F = 8 A; V_R = 400 V; dI_F/dt = 500 A/µs; T_j = 25 °C; Fig. 5		-	19	-	ns
I_{RM}	peak reverse recovery current	I_F = 10 A; V_R = 400 V; dI_F/dt = 500 A/µs; T_j = 100 °C		-	9.5	12	A
		I_F = 8 A; V_R = 400 V; dI_F/dt = 50 A/µs; T_j = 125 °C		-	1.5	5.5	A
Q_r	recovered charge	I_F = 1 A; V_R = 100 V; dI_F/dt = 100 A/µs; T_j = 25 °C		-	12	-	nC
V_{FR}	forward recovery voltage	I_F = 10 A; dI_F/dt = 100 A/µs; T_j = 25 °C; Fig. 6		-	8	10	V



(1) T_j = 150 °C; typical values

(2) T_j = 150 °C; maximum values

(3) T_j = 25 °C; maximum values

Fig. 4. Forward current as a function of forward voltage

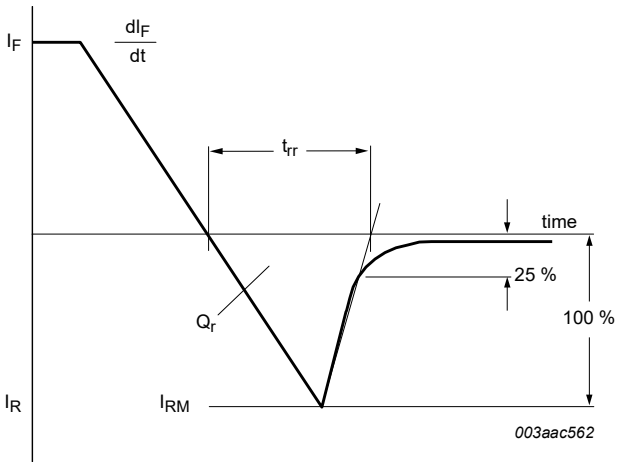


Fig. 5. Reverse recovery definitions; ramp recovery

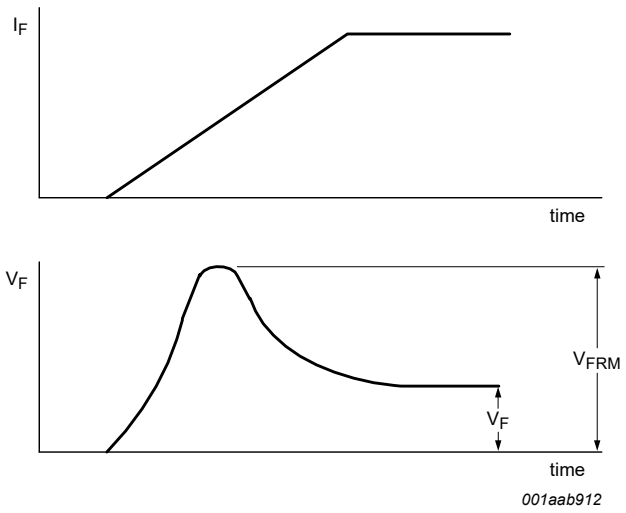
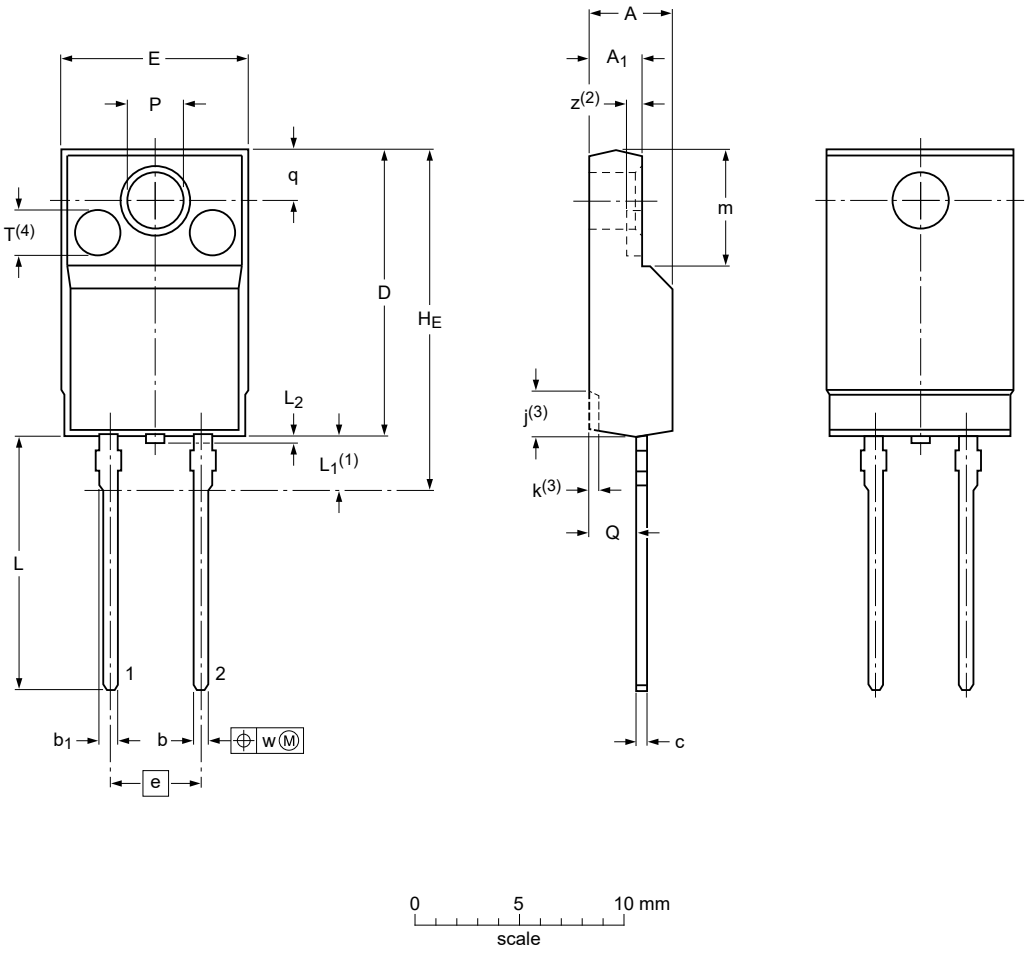


Fig. 6. Forward recovery definitions

12. Package outline

Plastic single-ended package; isolated heatsink mounted;
1 mounting hole; 2-lead TO-220 'full pack'

SOD113



Dimensions (mm are the original dimensions)

Unit		A	A_1	b	b_1	c	D	E	e	H_E max	$j^{(3)}$	$k^{(3)}$	L	$L_1{}^{(1)}$	L_2 max	m	P	Q	q	$T^{(4)}$	w	$z^{(2)}$
mm	max	4.6	2.9	0.9	1.1	0.7	15.8	10.3			2.7	0.6	14.4	3.3		6.5	3.2	2.6				
	nom								5.08	19.0					0.5				2.6	2.55	0.4	0.8
	min	4.0	2.5	0.7	0.9	0.4	15.2	9.7			1.7	0.4	13.5	2.8		6.3	3.0	2.3				

Notes
1. Terminals are uncontrolled within zone L1.
2. z is depth of T.
3. Dot lines area designs may vary.
4. Eject pin mark is for reference only.

sod113_po

Outline version	References				European projection	Issue date
	IEC	JEDEC	JEITA			
SOD113		2-lead TO-220F				~~07-06-08~~ 15-08-28

Fig. 7. Package outline TO-220F (SOD113)

13. Legal information

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Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
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